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| Inventor | W.G. Scott |
| Assignee | Micron Technology, Inc. |
| priority Group Art Unit | |
| priority Examiner | R. A. Booth |
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| Customer No. | 021567 |
| Title: Methods of Forming Transistor Gates; and Me | ethods of Forming Programmable |
| Read-Only Memory Constructions | · |
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PRELIMINARY AMENDMENT

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Mail Stop Patent Application Commissioner for Patents

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AMENDMENTS